PEI3I101 ANALOG ELECTRONICS CIRCUIT (3-0-2)

<u>MODULE – I</u>

MOS Field-Effect Transistor: Principle and Operation of FETs and MOSFETs; P-Channel and N-Channel MOSFET; Complimentary MOS; V-I Characteristics of E- MOSFET and D-MOSFET; MOSFET as an Amplifier and as a Switch. (4 Hours)

Biasing of BJTs: Load lines (AC and DC); Operating Points; Fixed Bias and Self Bias, DCBiaswith Voltage Feedback; Bias Stabilization; Examples.(4 Hours)

Biasing of FETs and MOSFETs: Fixed Bias Configuration and Self Bias Configuration, Voltage Divider Bias and Design (4 Hours)

<u>MODULE – II</u>

(12 Hours)

Small Signal Analysis of BJTs: Small-Signal Equivalent-Circuit Models; Small Signal Analysis of CE, CC, CB amplifiers. Effects of R_S and R_L on CE amplifier operation, Emitter Follower; Cascade amplifier, Darlington Connection and Current Mirror Circuits.

Small Signal Analysis of FETs:Small-Signal Equivalent-Circuit Model, Small SignalAnalysis of CS, CD, CG Amplifiers.Effects of R_{SIG} and R_L on CS Amplifier; Source Followerand Cascaded System.(6 Hours)

MODULE – III

(5 hours)

High Frequency Response of FETs and BJTs: High Frequency equivalent models andfrequency Response of BJTs and FETs; Frequency Response of CS Amplifier, FrequencyResponse of CE Amplifier.(5 Hours)

MODULE – IV (9 hours)

Feedback amplifier and Oscillators: Concepts of negative and positive feedback; Four Basic Feedback Topologies, Practical Feedback Circuits, Principle of Sinusoidal Oscillator, Wein-Bridge, Phase Shift and Crystal Oscillator Circuits. (4 Hours)

Operational Amplifier: Ideal Op-Amp, Differential Amplifier, Op-Amp Parameters, Noninverting Configurations, Open-loop and Closed-loop Gains, Differentiator and Integrator, Instrumentation amplifier. (5Hours)

(12 Hours)